

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	166	polycrystalline near silicon near island\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/15 14:54
L2	1205	pattern\$3 near polycrystalline near silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/15 14:55
L3	13	1 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/15 14:55
S1	6	(( "6256231" ) or ( "6181597" ) or ( "6081456" ) ).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	OFF	2004/12/14 09:10
S2	5	( "5768192"   "5793666"   "5844839"   "5875128"   "5936887" ).PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 09:11
S3	4	( "4380057"   "5768192"   "6011725"   "6044022" ).PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 09:13
S4	2	( "5168334"   "5768192" ).PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 09:14
S5	7	( "4360900"   "4373248"   "4377818"   "4451904"   "4597060"   "4768080"   "4774556" ).PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 09:15
S6	2	( "5568425"   "5768192" ).PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:18
S7	3179	257/2-5,16,52-63,646.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:18
S8	1	S7 and SONOS	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/15 15:00
S9	4	( "20030222318"   "4810673"   "6410210"   "6704188" ).PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:31
S10	9	( "4610771"   "5472829"   "5529524"   "5591566"   "5619097"   "5733712"   "5846693"   "5935765"   "6162588" ).PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:38

S11	570673	"257"/\$.ccls. "438"/\$.ccls. "365"/\$.ccls. "430"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 11:39
S12	780	S11 and SONOS	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 12:00
S13	831	S11 and SONOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 11:40
S14	23	S13 and (uv near \$2radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 11:43
S15	8	("20010046731"   "20030096475"   "5863462"   "5935705"   "6090358"   "6198216"   "6444568"   "6475895").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/14 11:56
S16	4	SONOS with (uv near \$2radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 12:01
S17	37	SONOS and (uv near \$2radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:48
S18	3105	SONOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:45
S19	1	S18 and ((polycrystalline near silicon) with (silicon near rich))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:56
S20	48264	(uv near \$2radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:48

S22	8	S20 and ((polycrystalline near silicon) and (silicon near rich))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 16:49
S23	73	S18 and (barrier near (film layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 17:42
S24	6	S18 and ((barrier near (film layer)) with (silicon near nitride))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 17:42
S33	8	((barrier near (film layer)) (silicon near nitride)) and SONOS and (metal near dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/12/14 17:45